

**Method For Producing High-Purity Silicon Carbide From Hydrocarbons
And Silicon Oxide Through Calcination**

Abstract

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The invention relates to a method for producing silicon carbide through reaction of silicon oxide and a carbon source comprising a hydrocarbon at high temperature, in particular to a technical method for producing silicon carbide or for producing compositions containing silicon carbide. The
10 invention further relates to a high-purity silicon carbide, to compositions containing the same, to the use thereof as a catalyst and for the production of electrodes and other items.

No Fig.